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Attorney's Docket No.: 10559-587001 / P12768

GP/2812

#4

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant : Been-Yih Jin et al.
Serial No. : 10/081,992
Filed : February 21, 2002
Title : NON-SILICON SEMICONDUCTOR AND HIGH-K GATE DIELECTRIC
METAL OXIDE SEMICONDUCTOR FIELD EFFECT TRANSISTORS

Art Unit : 2812
Examiner : Unknown

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Washington, D.C. 20231

INFORMATION DISCLOSURE STATEMENT

Applicants submit the references listed on the attached form PTO-1449, copies of which are enclosed.

This statement is being filed before the receipt of a first Office action on the merits.

Please apply any charges or credits to Deposit Account No. 06-1050.

Respectfully submitted,

Date: August 8, 2002

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I hereby certify under 37 CFR §1.8(a) that this correspondence is being deposited with the United States Postal Service as first class mail with sufficient postage on the date indicated below and is addressed to the Commissioner for Patents, Washington, D.C. 20231.

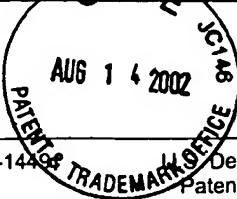
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Sheet 1 of 1

Substitute Form PTO-1449 (Modified)	Department of Commerce Patent and Trademark Office	Attorney's Docket No. 10559-587001	Application No. 10/081,992
		Applicant Been-Yih Jin et al.	
		Filing Date February 21, 2002	Group Art Unit 2812
		Information Disclosure Statement by Applicant (Use several sheets if necessary)	

(37 CFR §1.98(b))

Foreign Patent Documents or Published Foreign Patent Applications								
Examiner Initial	Desig. ID	Document Number	Publication Date	Country or Patent Office	Class	Subclass	Translation	
							Yes	No
	AA							
	AB							
	AC							
	AD							
	AE							

Other Documents (include Author, Title, Date, and Place of Publication)		
Examiner Initial	Desig. ID	Document
	AF	Chau et al., International Electron Devices Meeting 2000, San Francisco, CA, December 10-13, 2000.
	AG	Ghani et al., Symposium on VLSI Technology Digest of Technical Papers, Honolulu, HI, June 13-15, 2000.
	AH	Hubbard et al., "Thermodynamic stability of binary oxides in contact with silicon" J. Mater. Res., Vol. 11, No. 11, Nov. 1996.

Examiner Signature	Date Considered
EXAMINER: Initials citation considered. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.	